



DMMT5551/DMMT5551S

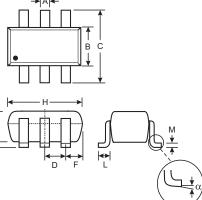
MATCHED NPN SMALL SIGNAL SURFACE MOUNT **TRANSISTOR**

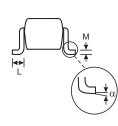
Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (DMMT5401)
- Ideal for Medium Power Amplification and Switching
- Intrinsically Matched NPN Pair (Note 1)
- 2% Matched Tolerance, hFE, VCE(SAT), VBE(SAT)
- 1% Matched Tolerance, Available (Note 2)
- Lead Free/RoHS Compliant (Note 5)
- "Green" Device, Note 6 and 7

Mechanical Data

- Case: SOT-26
- Case Material: Molded Plastic, "Green" Molding Compound, Note 7. UL Flammability Classification
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Copper leadframe).
- Marking (See Page 2): K4R & K4T
- Ordering & Date Code Information: See Page 2
- Weight: 0.006 grams (approximate)







DMMT5551S (K4T Marking Code) (K4R Marking Code)

В	1.50	1.70	1.60						
С	2.70	3.00	2.80						
D	_		0.95						
F	_		0.55						
Н	2.90	3.10	3.00						
J	0.013	0.10	0.05						
K	1.00	1.30	1.10						
L	0.35	0.55	0.40						
M	0.10	0.20	0.15						
α	0°	8°							
All Dimensions in mm									

SOT-26

Max

0.50

Typ

0.38

Min

0.35

Dim

Maximum Ratings @ $T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	180	V	
Collector-Emitter Voltage	V _{CEO}	160	V	
Emitter-Base Voltage	V _{EBO}	6.0	V	
Collector Current - Continuous (Note 3)	I _C	200	mA	
Power Dissipation (Note 3, 4)	Pd	300	mW	
Thermal Resistance, Junction to Ambient (Note 3)	$R_{ heta JA}$	417	K/W	
Operating and Storage and Temperature Range	T _j , T _{STG}	-55 to +150	°C	

DMMT5551

Notes: 1. Built with adjacent die from a single wafer.

- 2. Contact the Diodes, Inc. Sales department.
- 3. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 4. Maximum combined dissipation.
- 5. No purposefully added lead.
- 6. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php..
- 7. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition			
OFF CHARACTERISTICS (Note 8)								
Collector-Base Breakdown Voltage	V _{(BR)CBO}	180	_	V	$I_C = 100 \mu A, I_E = 0$			
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	160	_	V	$I_C = 1.0 \text{mA}, I_B = 0$			
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	6.0	_	V	$I_E = 10 \mu A, I_C = 0$			
Collector Cutoff Current	I _{CBO}	_	50	nA μA	V _{CB} = 120V, I _E = 0 V _{CB} = 120V, I _E = 0, T _A = 100°C			
Emitter Cutoff Current	I _{EBO}	_	50	nA	$V_{EB} = 4.0V, I_{C} = 0$			
ON CHARACTERISTICS (Note 8)								
DC Current Gain (Note 9)	h _{FE}	80 80 30	250 —	_	$\begin{array}{l} I_{C} = 1.0 \text{mA}, \ V_{CE} = 5.0 \text{V} \\ I_{C} = \ 10 \text{mA}, \ V_{CE} = 5.0 \text{V} \\ I_{C} = \ 50 \text{mA}, \ V_{CE} = 5.0 \text{V} \end{array}$			
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.15 0.20	V	I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA			
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	1.0	V	I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA			
SMALL SIGNAL CHARACTERISTICS								
Output Capacitance	C _{obo}	_	6.0	pF	V _{CB} = 10V, f = 1.0MHz, I _E = 0			
Small Signal Current Gain	h _{FE}	50	250	_	V _{CE} = 10V, I _C = 1.0mA, f = 1.0kHz			
Current Gain-Bandwidth Product	f⊤	100	300	MHz	$V_{CE} = 10V, I_{C} = 10mA,$ f = 100MHz			
Noise Figure	NF	_	8.0	dB	$V_{CE} = 5.0V, I_{C} = 200\mu A, R_{S} = 1.0k\Omega, f = 1.0kHz$			

Ordering Information (Note 7 & 10)

Device	Packaging	Shipping			
DMMT5551-7-F	SOT-26	3000/Tape & Reel			
DMMT5551S-7-F	SOT-26	3000/Tape & Reel			

Notes:

- 7. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.
- 8. Short duration test pulse used to minimize self-heating effect.
 - 9. The DC Current Gain, hFE, (matched at I_C = 10mA and V_{CE} = 5V) Collector Emitter Saturation Voltage, V_{CE(SAT)}, and Base Emitter Saturation Voltage, V_{BE(SAT)} are matched with typical matched tolerances of 1% and maximum of 2%.
- 10. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

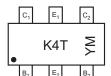
Marking Information



K4R = DMMT5551 Product Type Marking Code YM = Date Code Marking

Y = Year ex: P = 2003

M = Month ex: 9 = September



K4T = DMMT5551S Product Type Marking Code

YM = Date Code Marking Y = Year ex: P = 2003

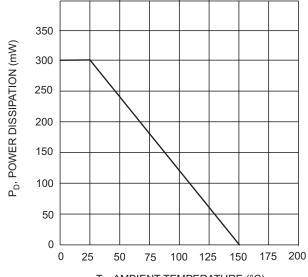
M = Month ex: 9 = September

Date Code Key

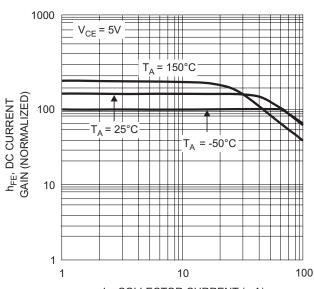
Year	2003	2004	2005	2006	2007	2008	2009
Code		R	S	Т	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

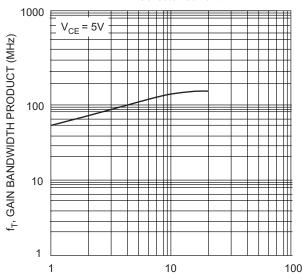




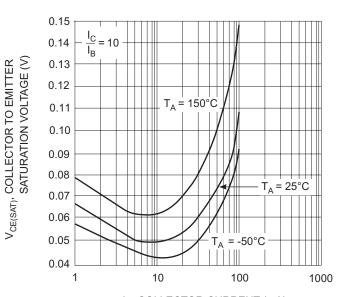
T_A, AMBIENT TEMPERATURE (°C) Fig. 1, Max Power Dissipation vs Ambient Temperature



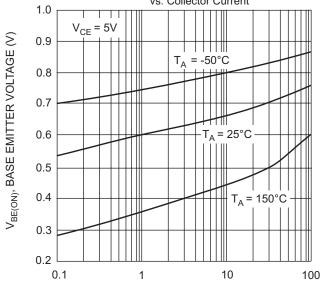
I_C, COLLECTOR CURRENT (mA) Fig. 3, DC Current Gain vs Collector Current



I_C, COLLECTOR CURRENT (mA) Fig. 5, Gain Bandwidth Product vs. Collector Current



I_C, COLLECTOR CURRENT (mA)
Fig. 2, Collector Emitter Saturation Voltage
vs. Collector Current



I_C, COLLECTOR CURRENT (mA) Fig. 4, Base Emitter Voltage vs. Collector Current



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